

GEM & TimePix

Larger Pixels, New Insights

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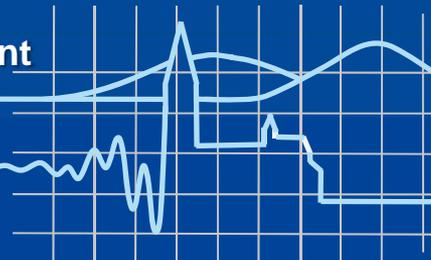
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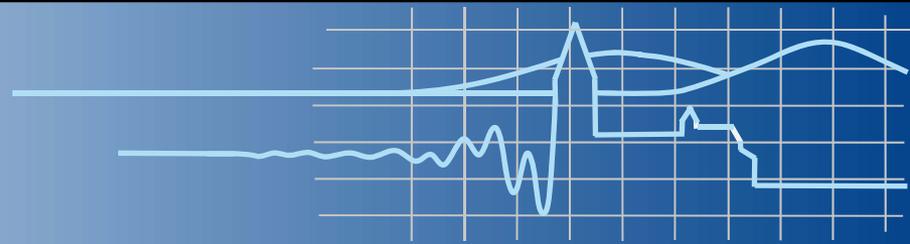
Albert-Ludwigs-Universität Freiburg



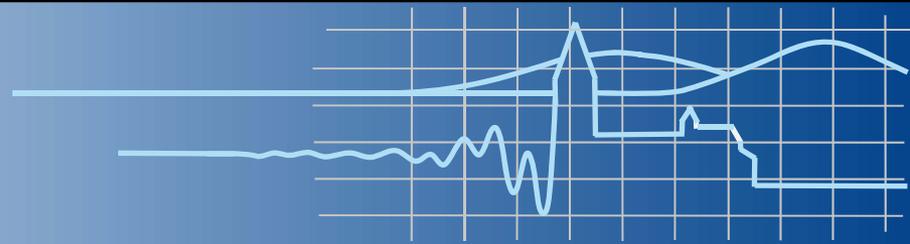
Physics Department

Albert-Ludwigs-
University Freiburg





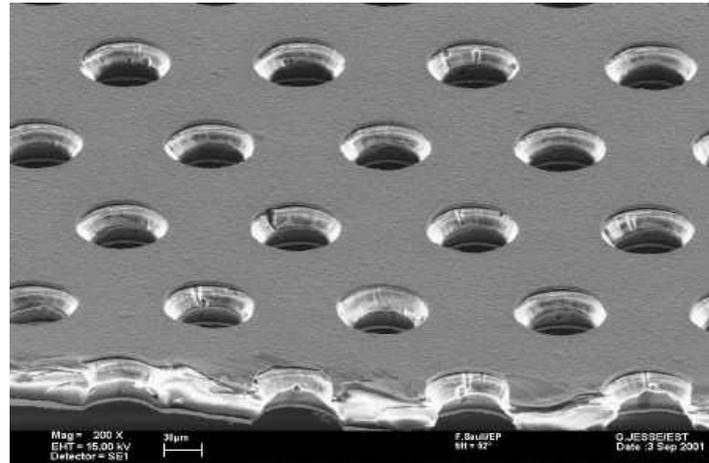
- **Introduction**
 - » GEMs
 - » Pixel enlargement
 - » Experimental setup
- **Studies with 1x1 and 2x2 chips**
 - » Comparison of effective threshold for both chips.
 - » Gain Estimation
 - » Studies with TOT calibration of individual pixels.
- **Summary**
- **Future Plans**



Principle

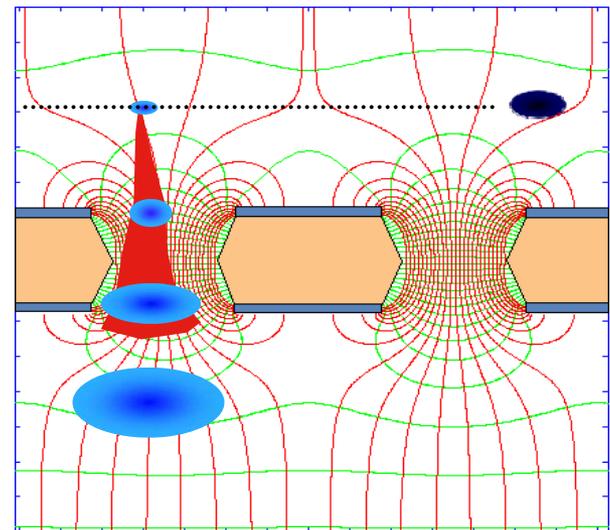
- 2 layers Cu each 5 μm thick, separated from each other by 50 μm Kapton.
- Conical etched holes largest $\varnothing 70 \mu\text{m}$, diagonal distance of holes 140 μm .

F. Sauli, <http://www.cern.ch/GDD>



Triple-GEM-setup

- Gas gain up to 10^5 in ArCO_2
 - ⇒ Necessary because charge is typically spread over several pixels ($\gg 50$ pixels)
- Minimizing the positive ion backdrift
- Localized region of amplification
- Reliable operation, only few sparks

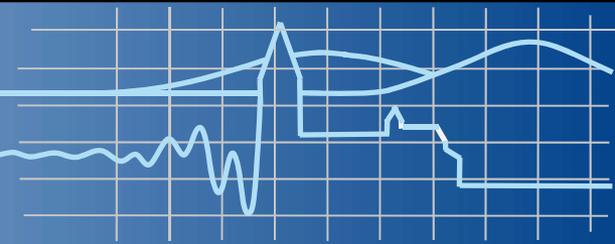


Motivation for larger Pixels



- **Charge of cluster is spread over several pixels:**
 - Reduces number of e^- per channel.
 - Increases effective threshold.
 - Requires high gas gain to detect minimum ionizing particles.
- **Large pixels:**
 - Collect more charge per pixel \Rightarrow Reduce effective threshold.
 - Need less gas gain \Rightarrow Smaller number of positive ions.
 - Optimize pixel size versus spatial resolution.
 - Strong diffusion between cascaded GEM stack.
 \Rightarrow Very small pixels not necessary

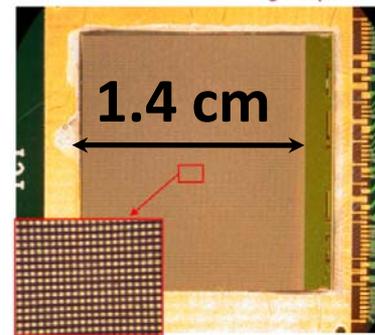
Pixel Enlargement IZM



universität**bonn**

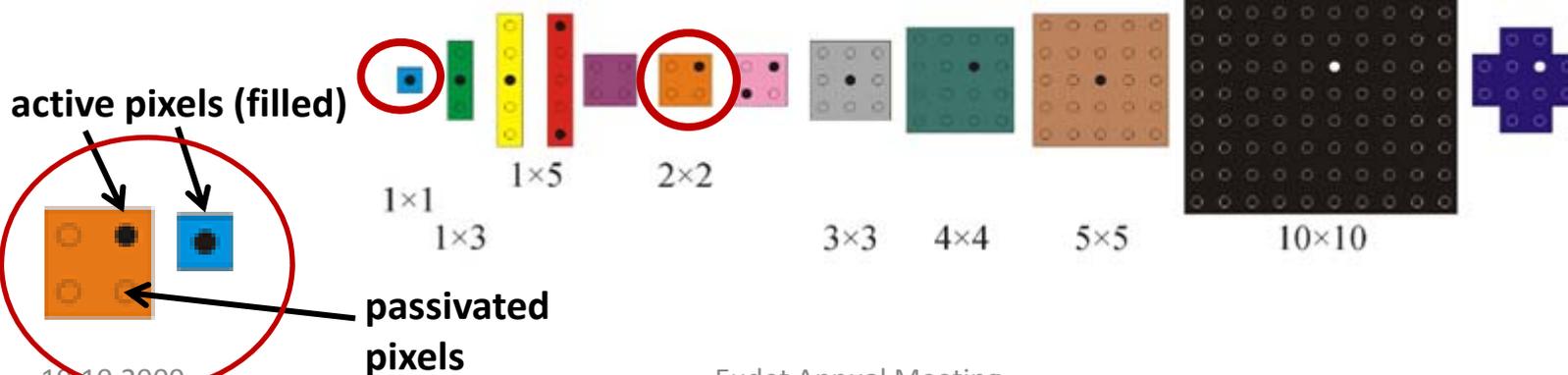
Dimensions & Features

- 256 x 256 pixels²
- 55 x 55 μm^2 pixel size
- 14 x 14 mm² active area
- **Measures Time Over Threshold (TOT)**
- **External test pulse can be injected in pixels**

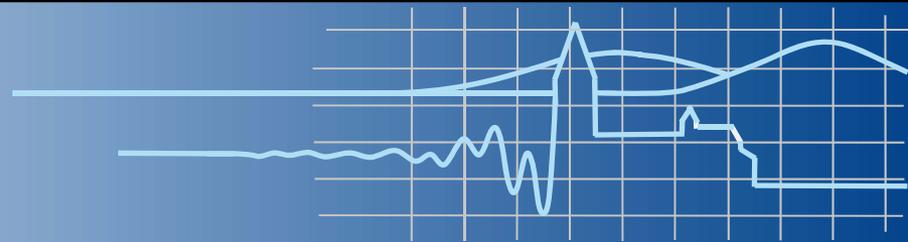


TimePix is used as highly segmented charge collecting anode

- Post processing of complete *wafer from Bonn* group by IZM Berlin:
 - » Different pixel sizes
 - » Different pixel geometries
- Two post processed TimePix tested
 - **1x1:** pixel metallization extended from $\approx 20 \times 20 \mu\text{m}^2$ to $50 \times 50 \mu\text{m}^2$
 - **2x2:** pixel size extended to $105 \times 105 \mu\text{m}^2$ by passivating 3 out of 4 pixels and adding metallization

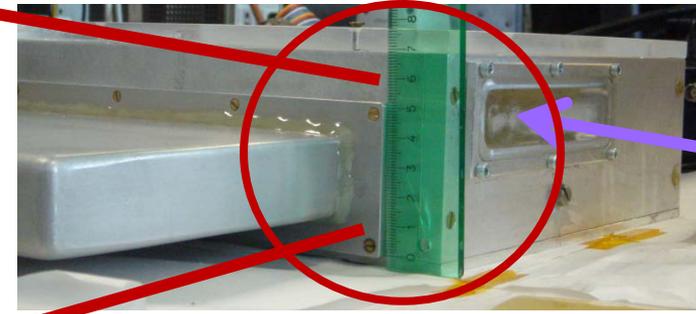
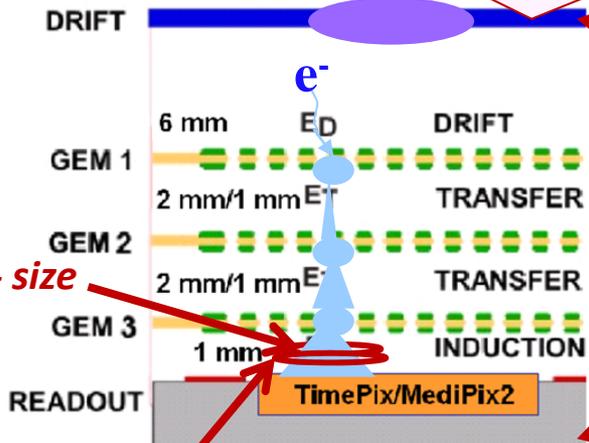


Test Setup



schematic view of the stack
from side

laser spot $\varnothing \approx 0.7$ cm



σ cluster-size

Transverse diffusion between GEMs leads to spread of charge across several pixel ($\gg 50$)

Potentials and fields:

$\Delta V_{GEM} = 317$ V:

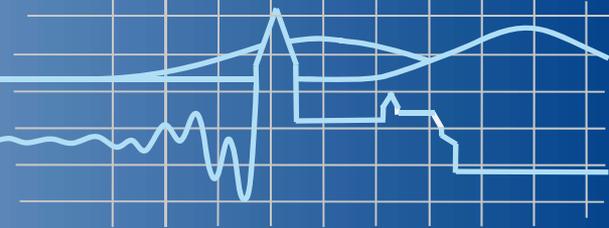
- $E_D = 0.85$ kV/cm
- $E_T = 2.54$ kV/cm
- $E_i = 3.57$ kV/cm

$\Delta V_{GEM} = 375$ V:

- $E_D = 1.00$ kV/cm
- $E_T = 3.00$ kV/cm
- $E_i = 4,21$ kV/cm

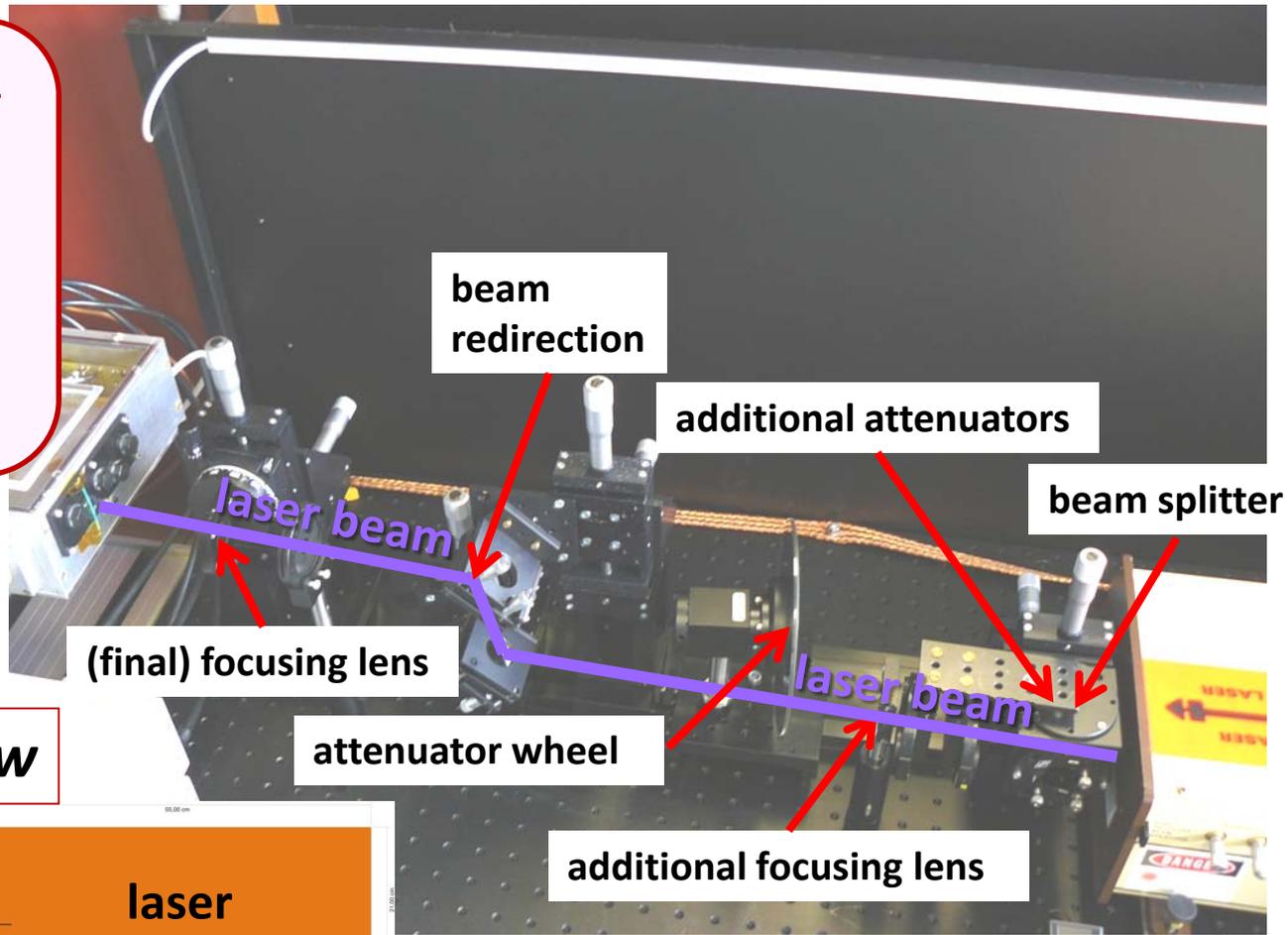
Voltage across GEMs (ΔV_{GEM}) equal for all three GEMs

Test Setup with Laser

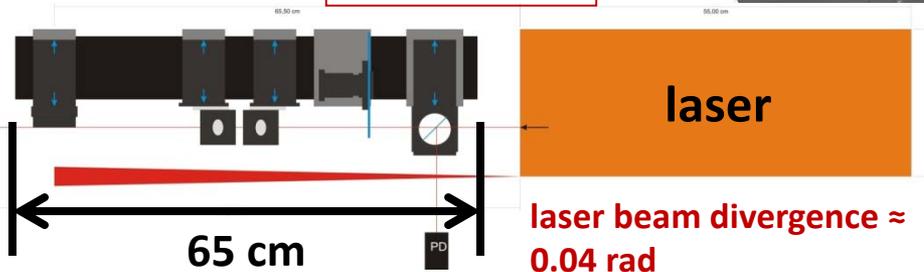


Readout interfaces:

- **USB interface:**
 - »80MHz clock
 - »Used for 2x2 chip
- **Muros interface:**
 - »37MHz clock
 - »Used for 1x1 chip



top view

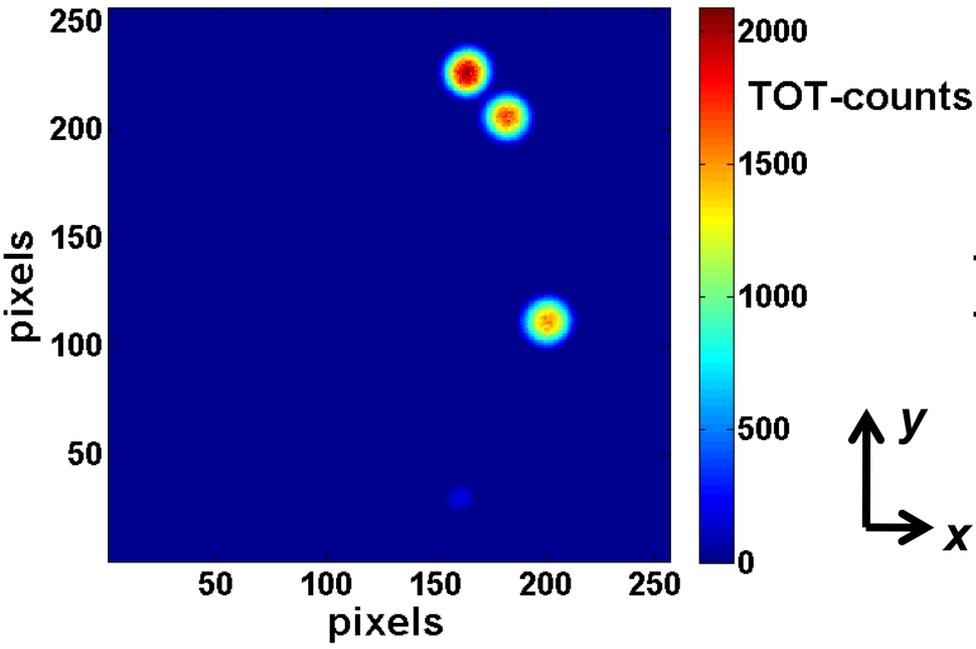


Events with Iron Fe^{55}



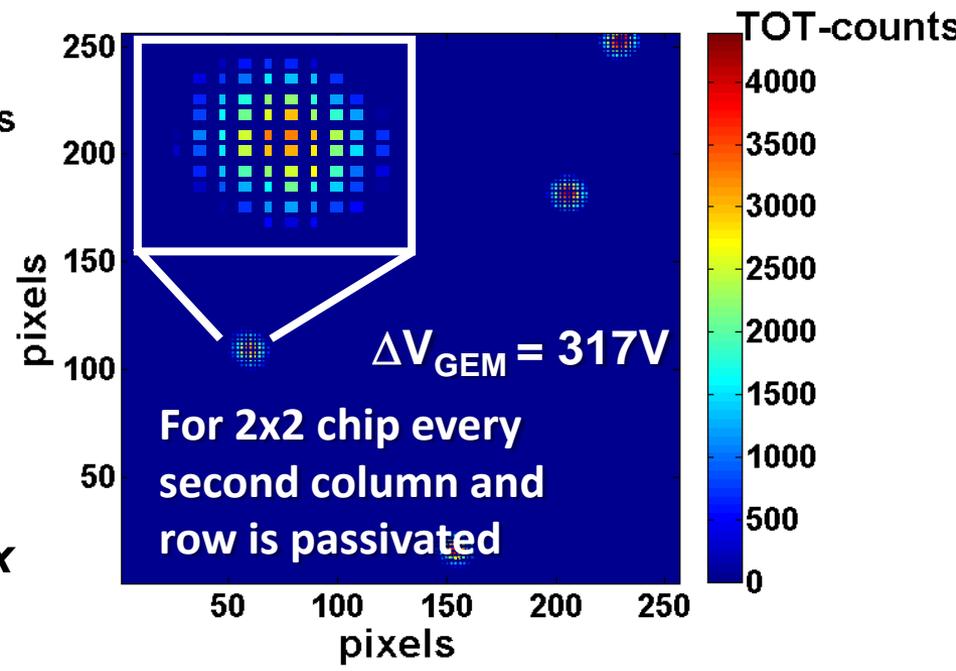
Fe^{55} clusters with 1x1

TimePix (Muros)



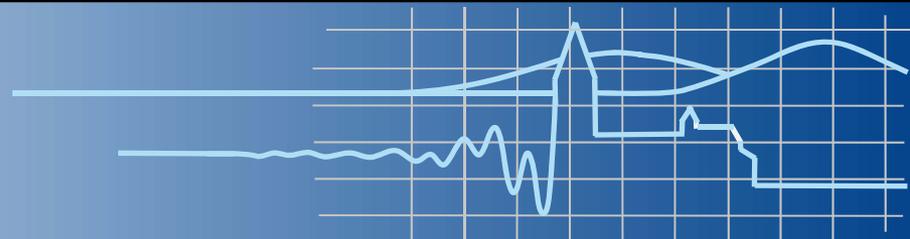
Fe^{55} clusters with 2x2

TimePix (USB)

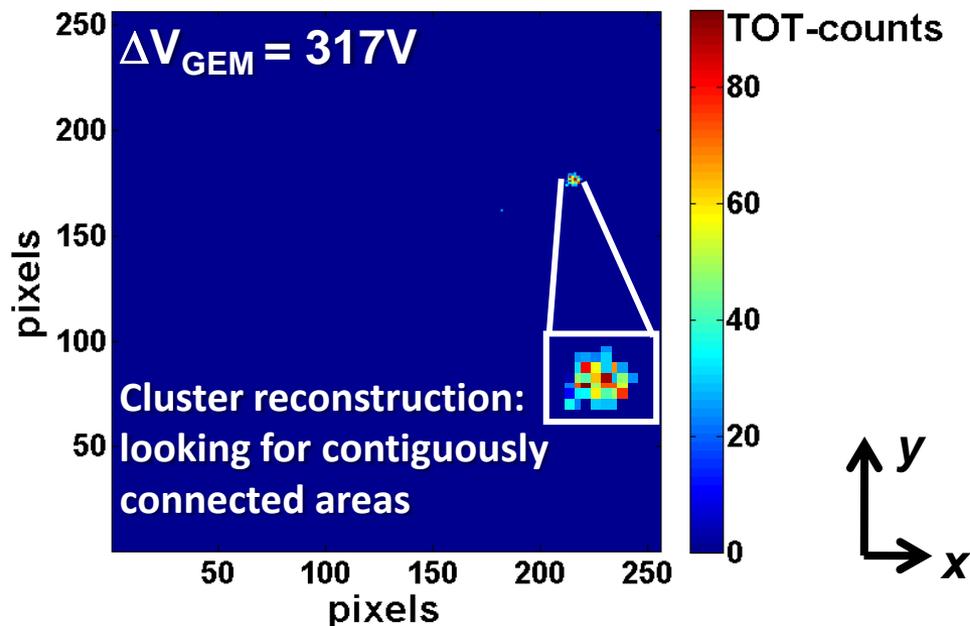


•USB (80MHz clock) used for 2x2 } TOT not directly comparable : has to apply factor 80/37 to 1x1 TOT values
•Muros (37MHz) used for 1x1

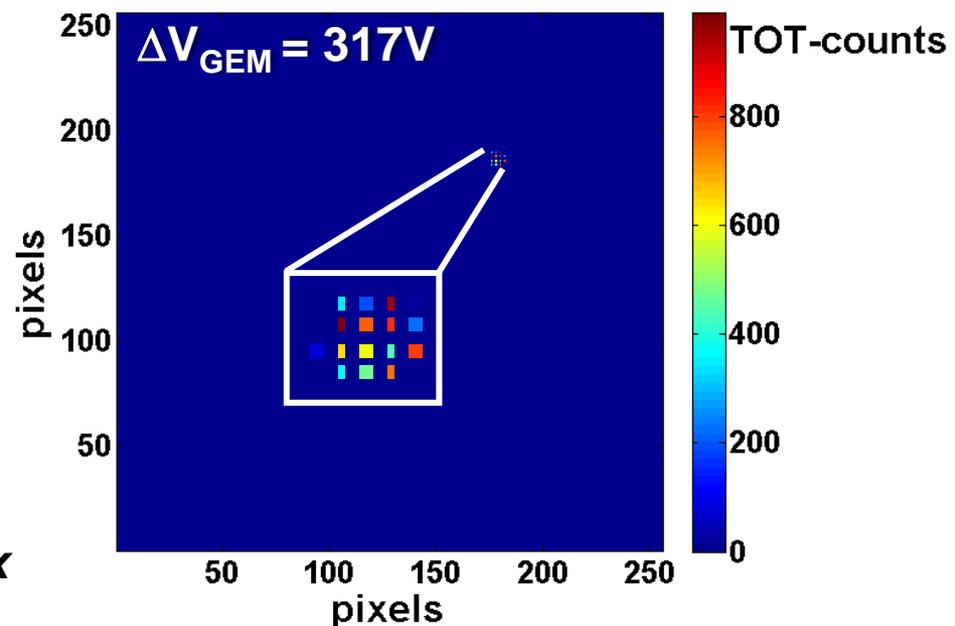
Events with Laser



1x1 event

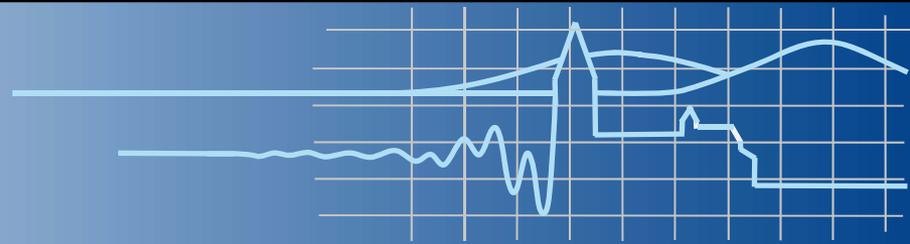


2x2 event

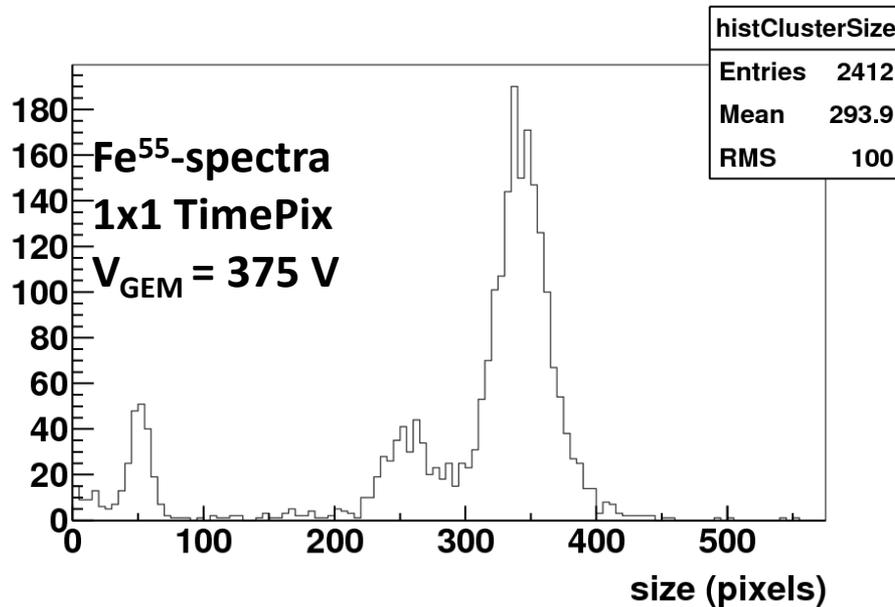


- Use Laser to characterize response of a test device using few or single primary e^-
- Following cluster information are reconstructed for *both sources*: Laser and Fe^{55}
 - » ClusterSize = number of pixels in a cluster
 - » ClusterCentroid = geometric center of cluster (x,y)
 - » TotVolume = sum of all TOT counts in a cluster
 - » TotAtCluster = TOT value at the cluster centroid
 - » Eccentr = eccentricity of a cluster

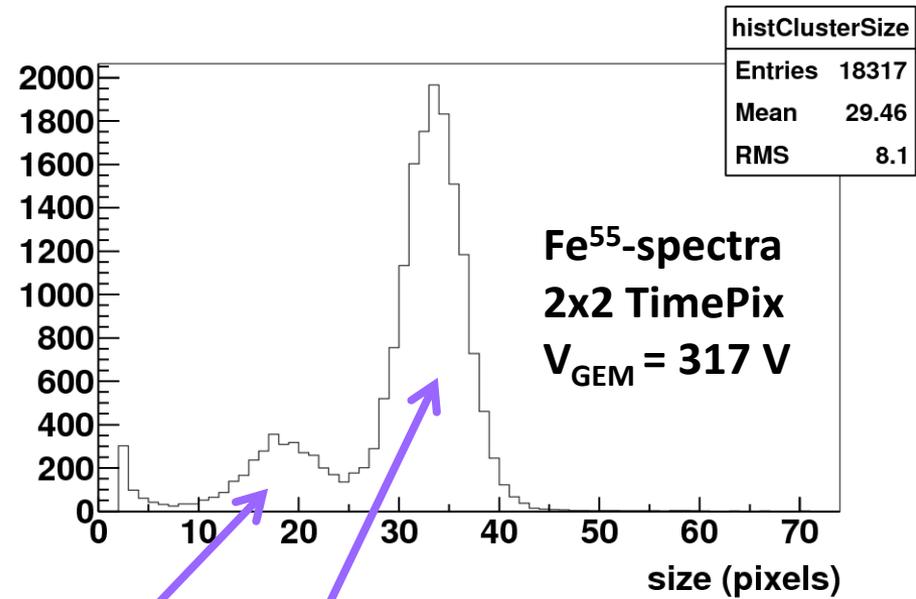
ClusterSize-Spectra



1x1 spectrum



2x2 spectrum

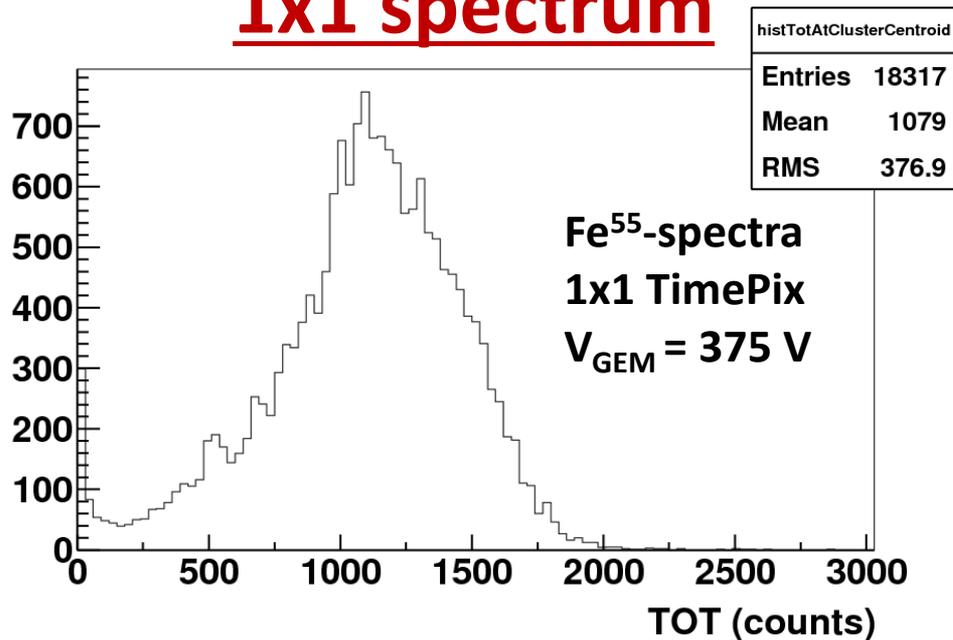


Typical argon spectra with *escape* and *photo* peak

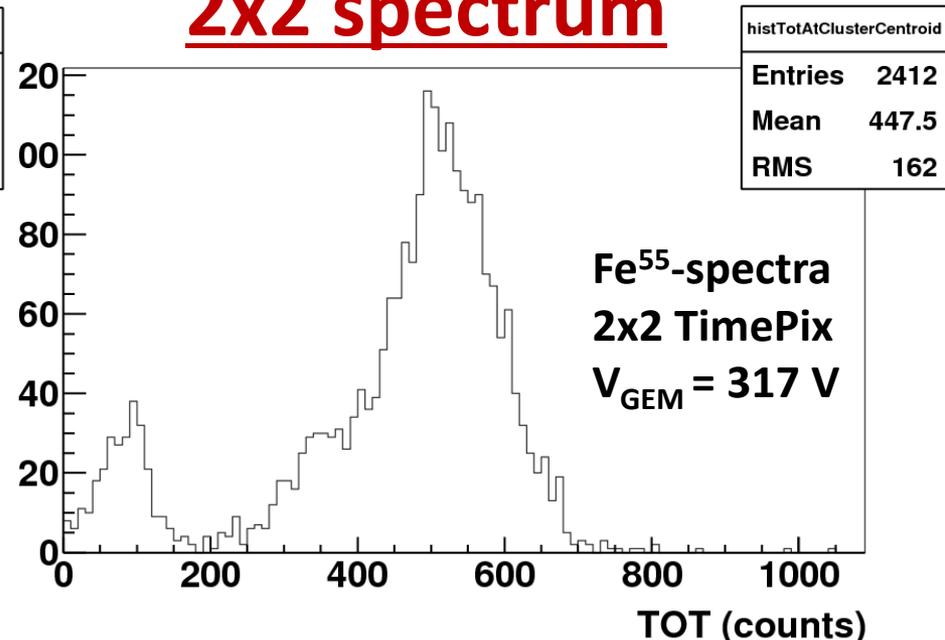
- Factor 10 difference in cluster size.
- For now: Take only TOT value at center of cluster to compare.
effective threshold of 1x1 and 2x2 chips.
⇒ value independent of cluster size

TOT at Cluster Centroid-Spectra

1x1 spectrum

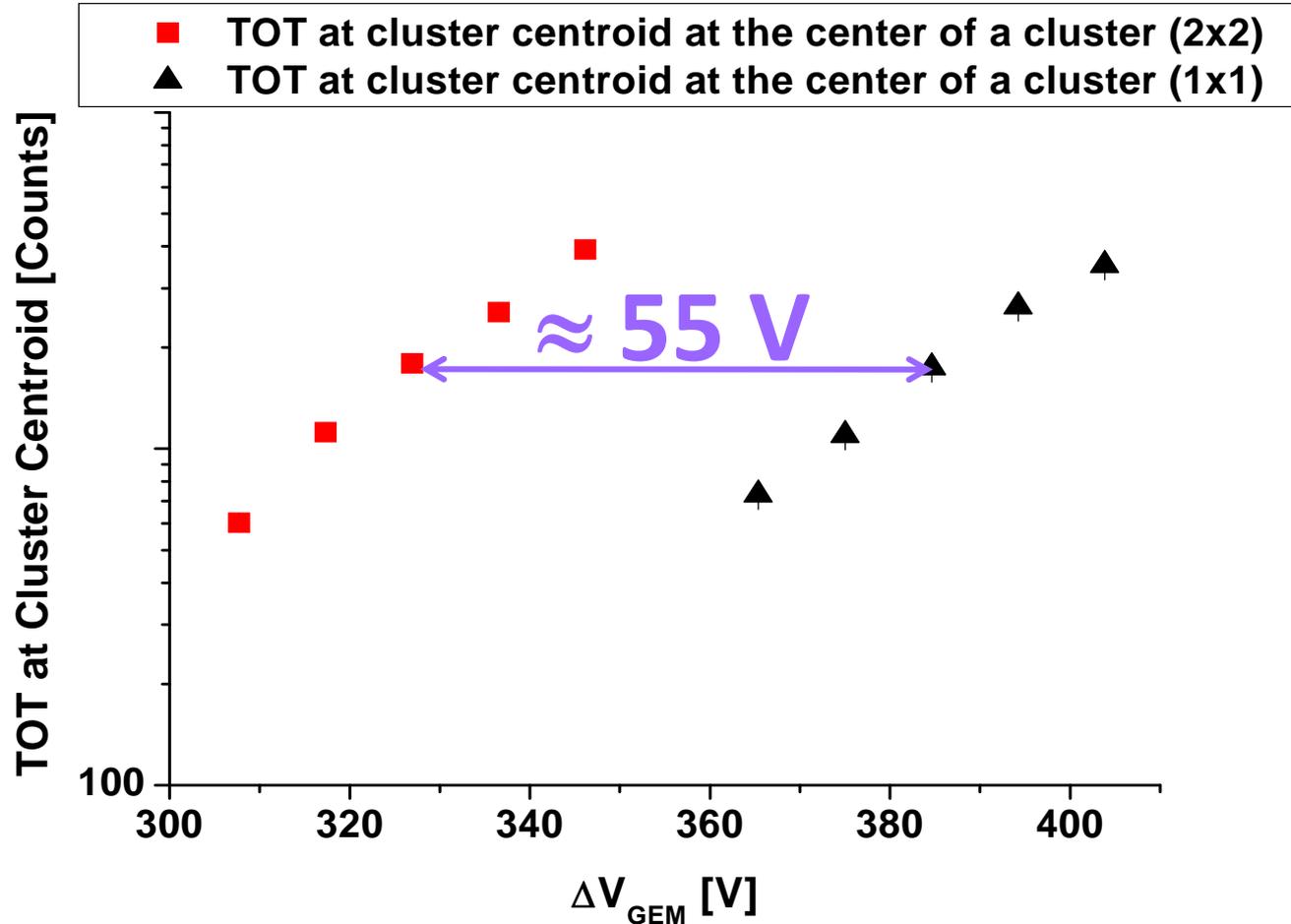
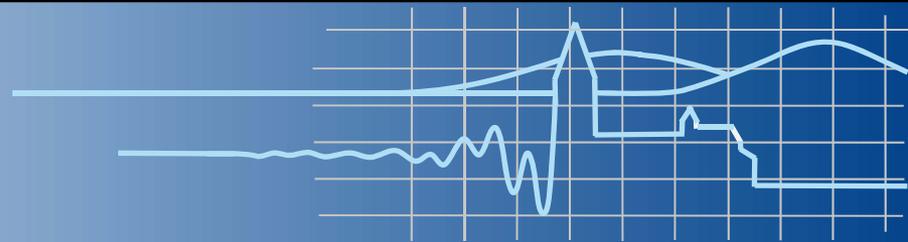


2x2 spectrum



- To compare 1x1 and 2x2: Determine peak position for different GEM voltages.
- Look for same TOT value of 1x1 and 2x2 and estimate difference in ΔV_{GEM} .
- Problem:
 - » Different thresholds for 1x1 and 2x2 TimePix
 - » Different readout interfaces \Rightarrow different clocks must be corrected
 - » Other systematic uncertainties are investigated

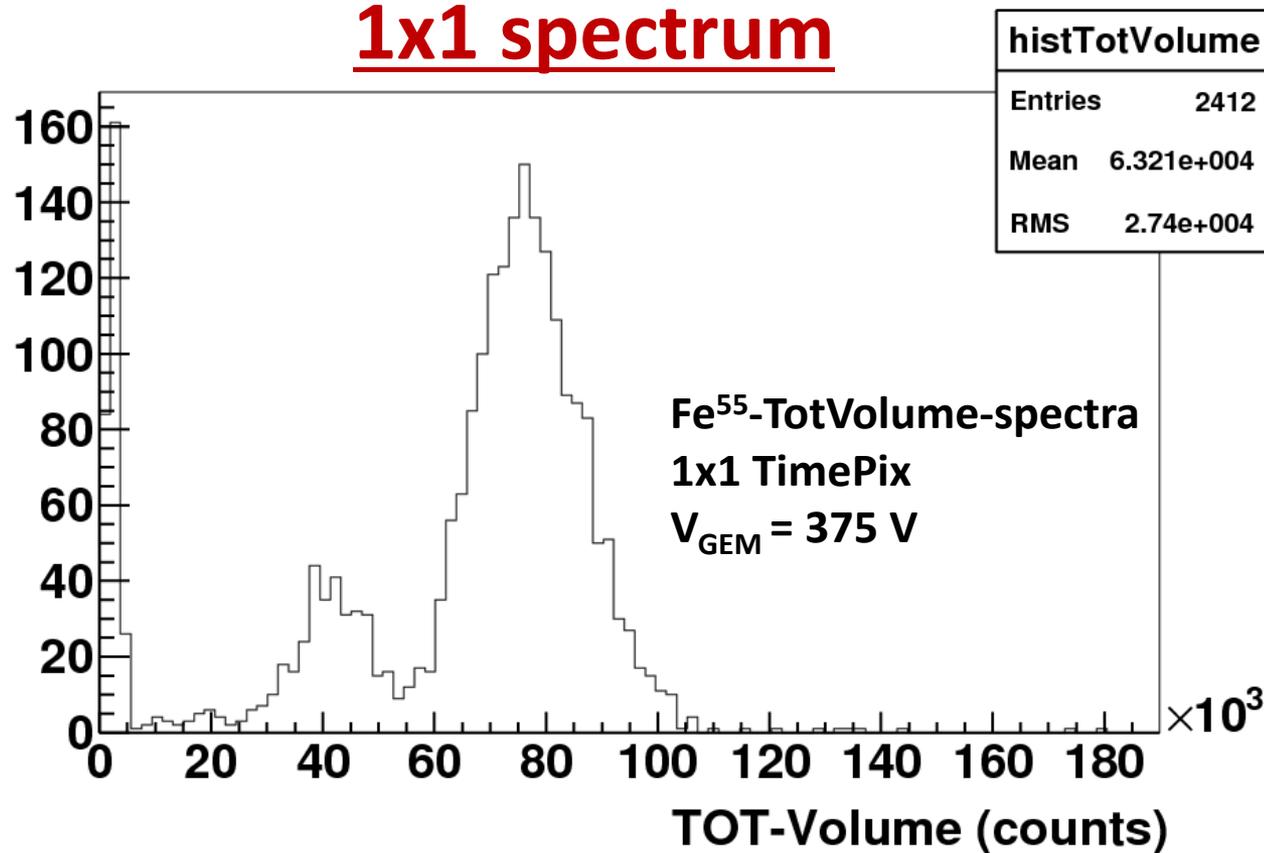
TOT Counts at Cluster Centroid vs. ΔV_{GEM}



- To account for different clocks 1x1 results are corrected with factor 80/37.
- For about same TOT value $\approx 55\text{V}$ smaller ΔV_{GEM}
- Lower effective threshold \Rightarrow Less backflow of positive ions into drift volume.

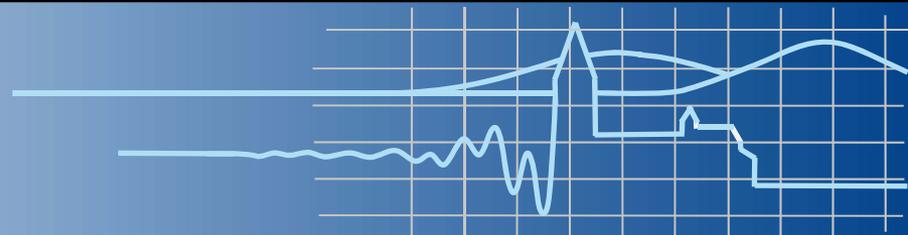
TotVolume-Spectra 1x1

1x1 spectrum



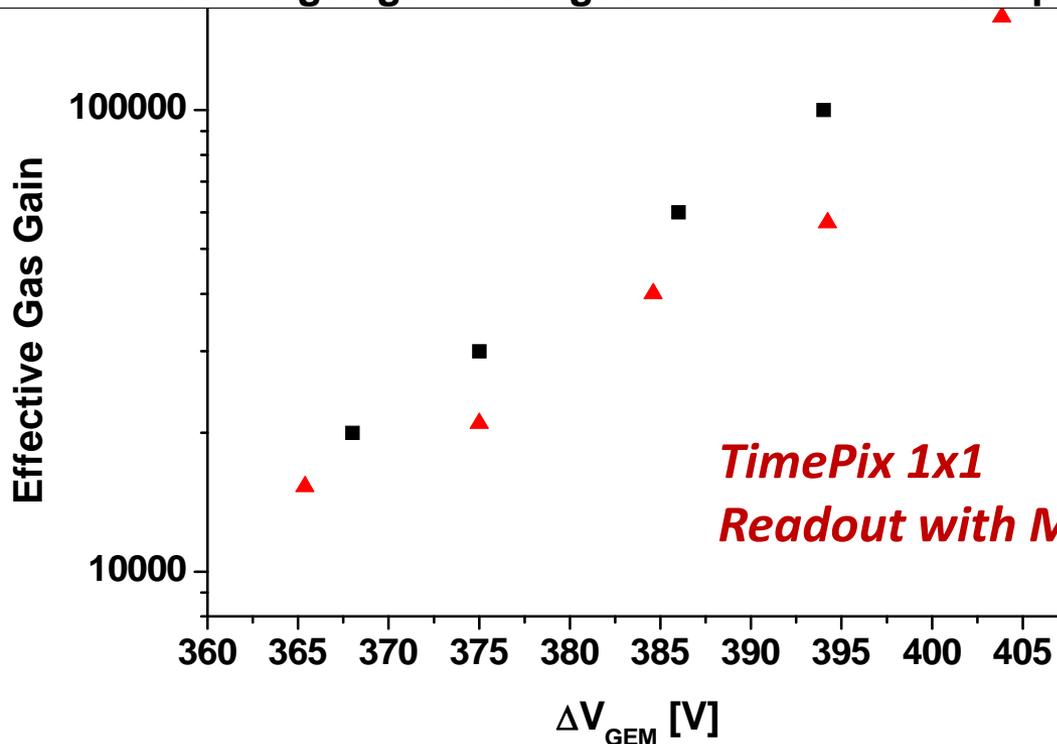
- Goal: Measure effective gain ⇒ Determine TotVolume at photo peak.
- But: Need conversion from TOT to charge in e⁻ ⇒ calibrate TOT of TimePix using external test pulses.

Gain Estimation



- “Recipe” to calibrate TOT with test pulses:
 - » Charge of injected test pulses (TimePix-Manual): $Q = 50[e^-/V] \times \text{TestPulse}[V]$
 - » Conversion factor from TOT count to charge (“chipwise”).
- Estimate Charge deposition from **TOT volume** of a cluster.

- ▲ Effective gas gain with overall chip calibration
- Effective gas gain from gdd.web.cern.ch for a triple GEM



*TimePix 1x1
Readout with Muros at 37MHz*

New approach for calibration

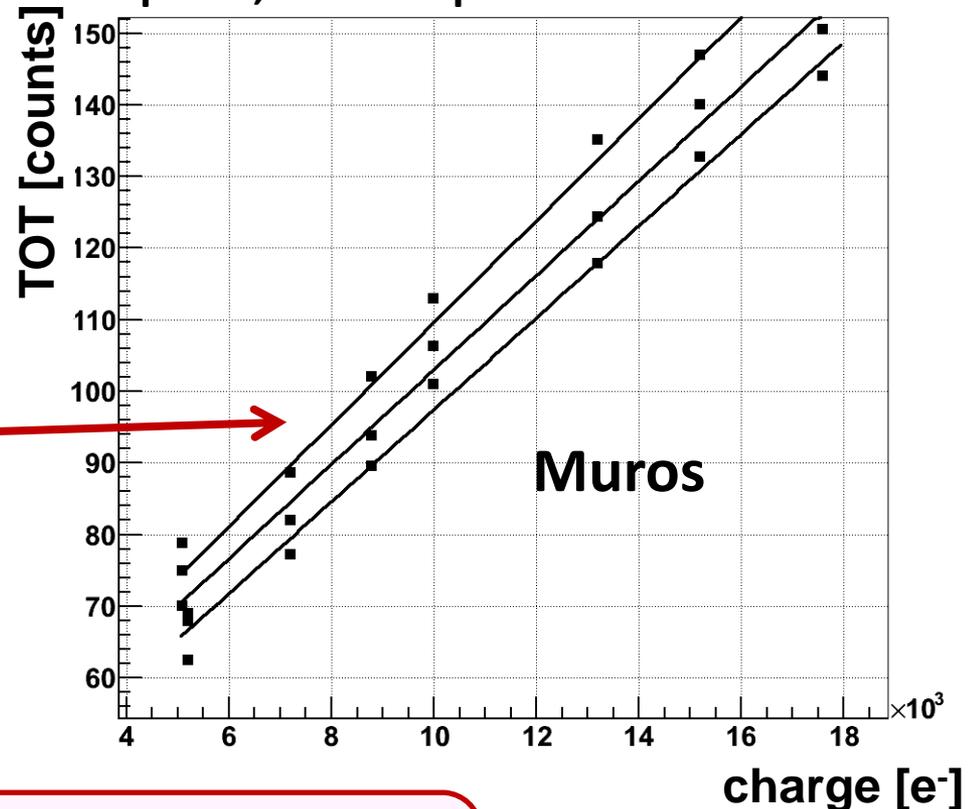
- TOT depends linear on the deposited charge Q:

$$\text{TOT} = b \cdot Q + a$$

- Until now: Calibration with test pulses is done chipwise.

⇒ But every Pixel has its own response function

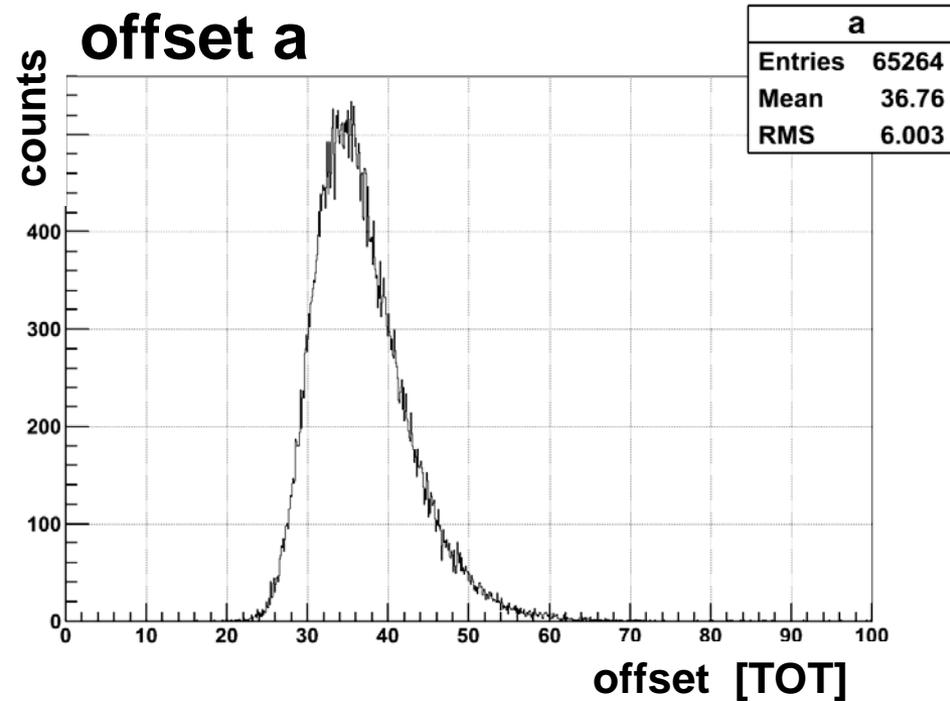
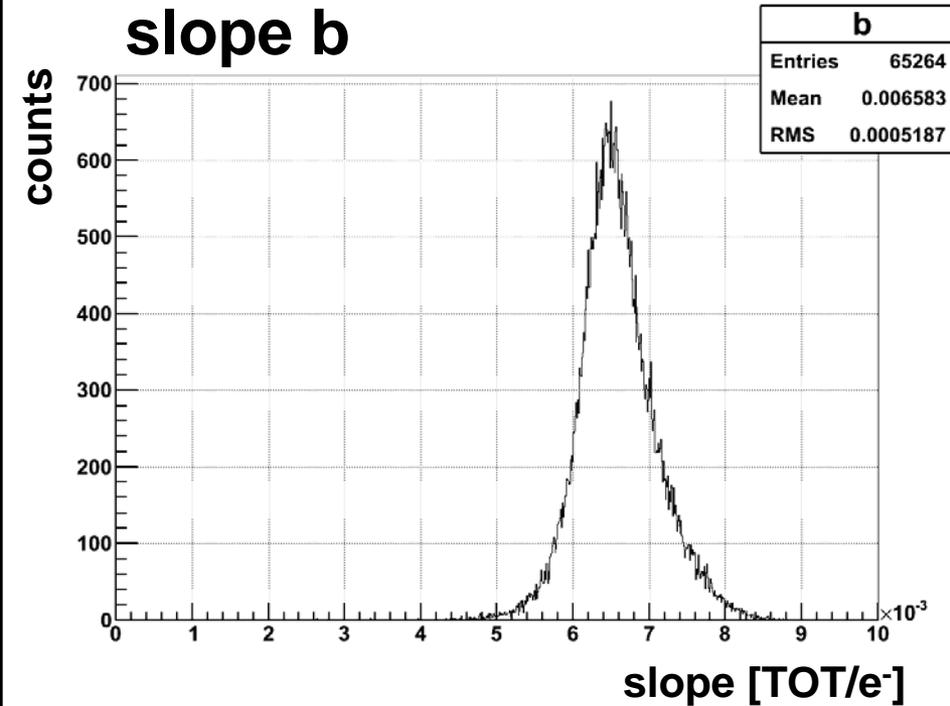
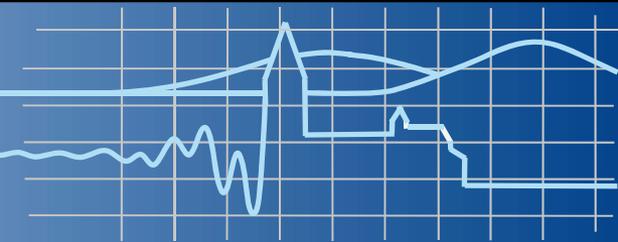
Calibration curves for three different pixels, same chip:



Is there a benefit in calibrating single pixels?

Is there a difference between USB and Muros?

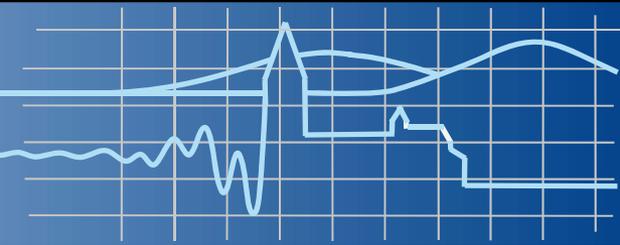
Muros with Test Pulses



$$\text{TOT} = b \cdot Q + a$$

- Results indicate: Muros small variations in pixel response.
- Fluctuations for time being not separable from statistical deviations.

Muros & USB - Comparison



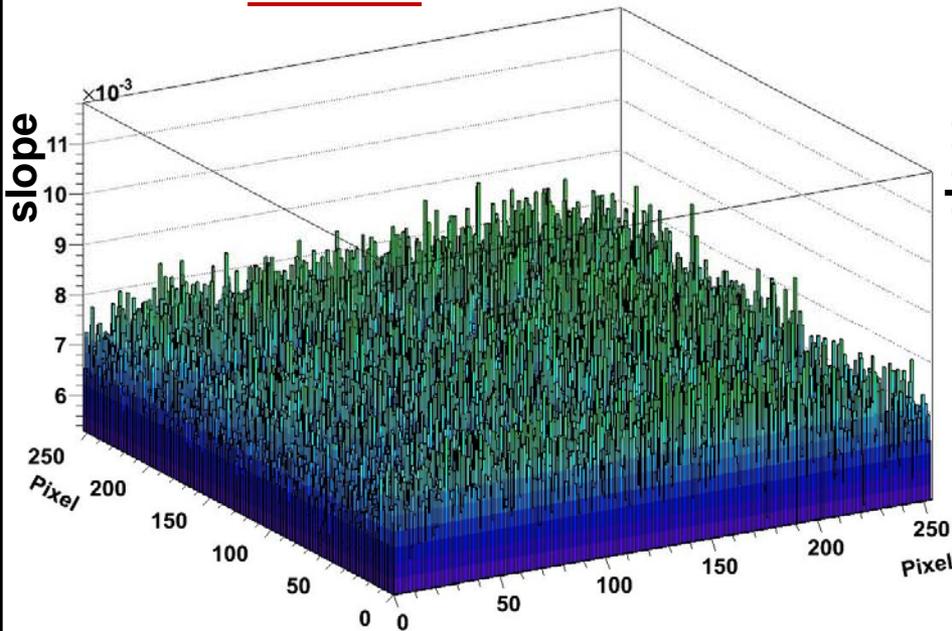
- Are these distribution homogenous across the chip?
- Are these distributions the same for Muros and USB interfaces?

Our experience shows:

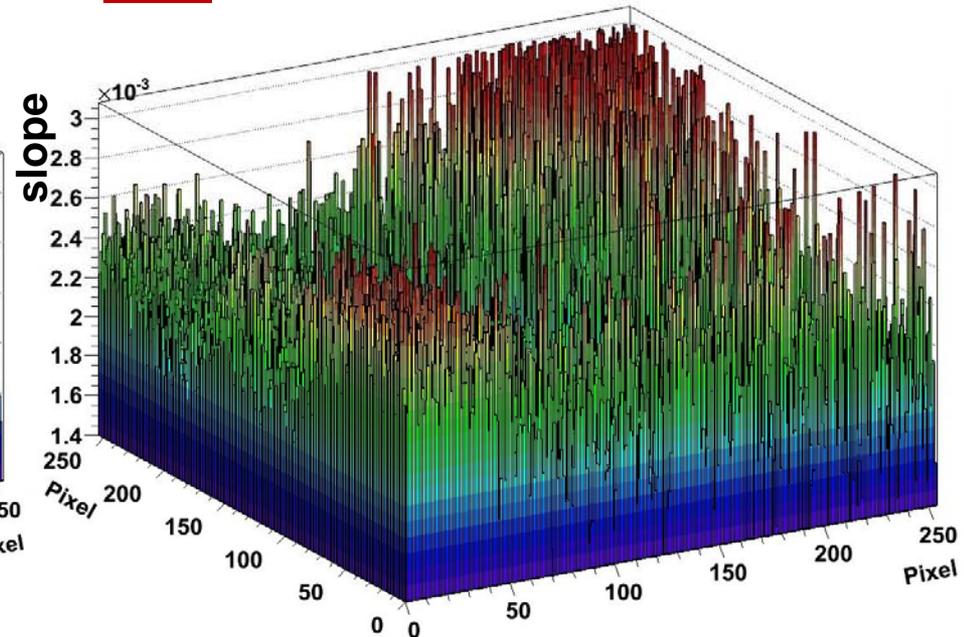
USB interface:

- more noisy
- inhomogeneous pixel response

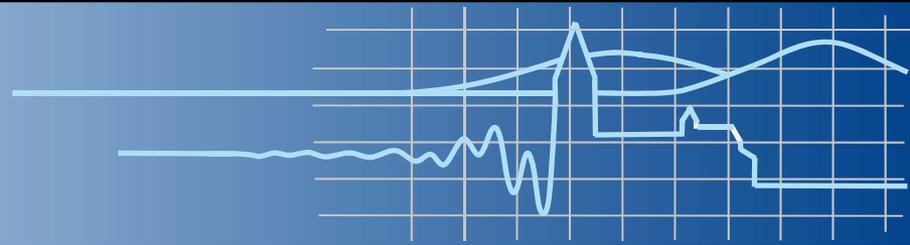
Muros



USB

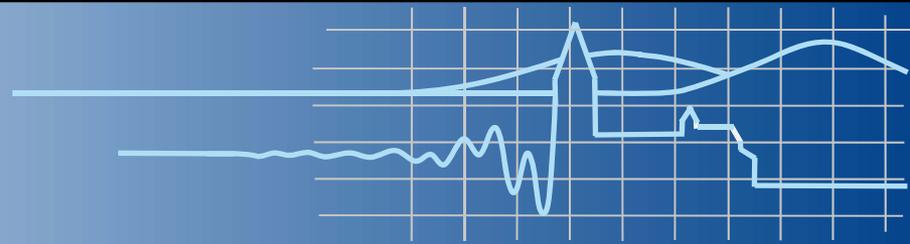


Summary

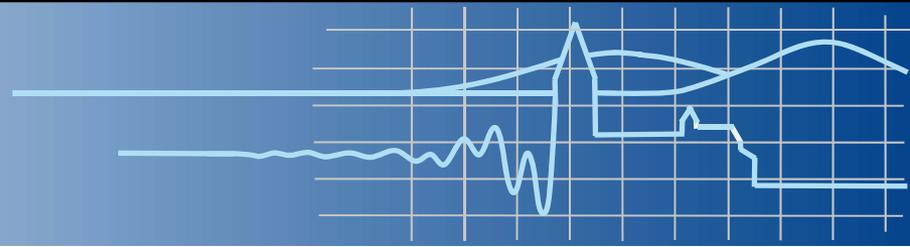


- Pixel enlargement **reduces effective threshold.**
- Gain measurement - nice agreement between reference from GDD at CERN and TimePix:
 - » Systematic errors are under study
 - » Calibration with TimePix 2x2 will be done soon
 - ⇒ Estimate gain at lower ΔV_{GEM}
- Problems with USB are only present for measurements with test pulses
- **Refined and more detailed analysis in progress**

Future Plans

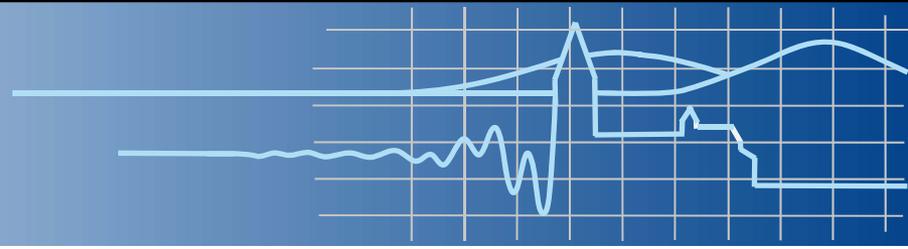


- **Tests with new chamber and 8 Channel HV:**
 - » Further study 1x1 , 1x3, 1x5, 2x2, 3x3, 4x4... TimePix chips
 - » Parameter scan to **find optimal settings** V_{GEM} , E_{Drift} , $E_{Transfer}$ and $E_{induction}$
 - » **Test ageing properties** of material used for passivation, pixel enlargement and possibly Ingrids.
- **New gate generator will create very stable shutter signal for TimePix**
 - » **Less than 1ns jitter**
 - » Allows very exact determination of precision in time for any device under test (e.g. TOT or TIME like measurements for Gossip/TimePix2).
- **Laser test bench together with radioactive sources allows accurate characterization of all possible combinations of MPGDs and pixel readout**



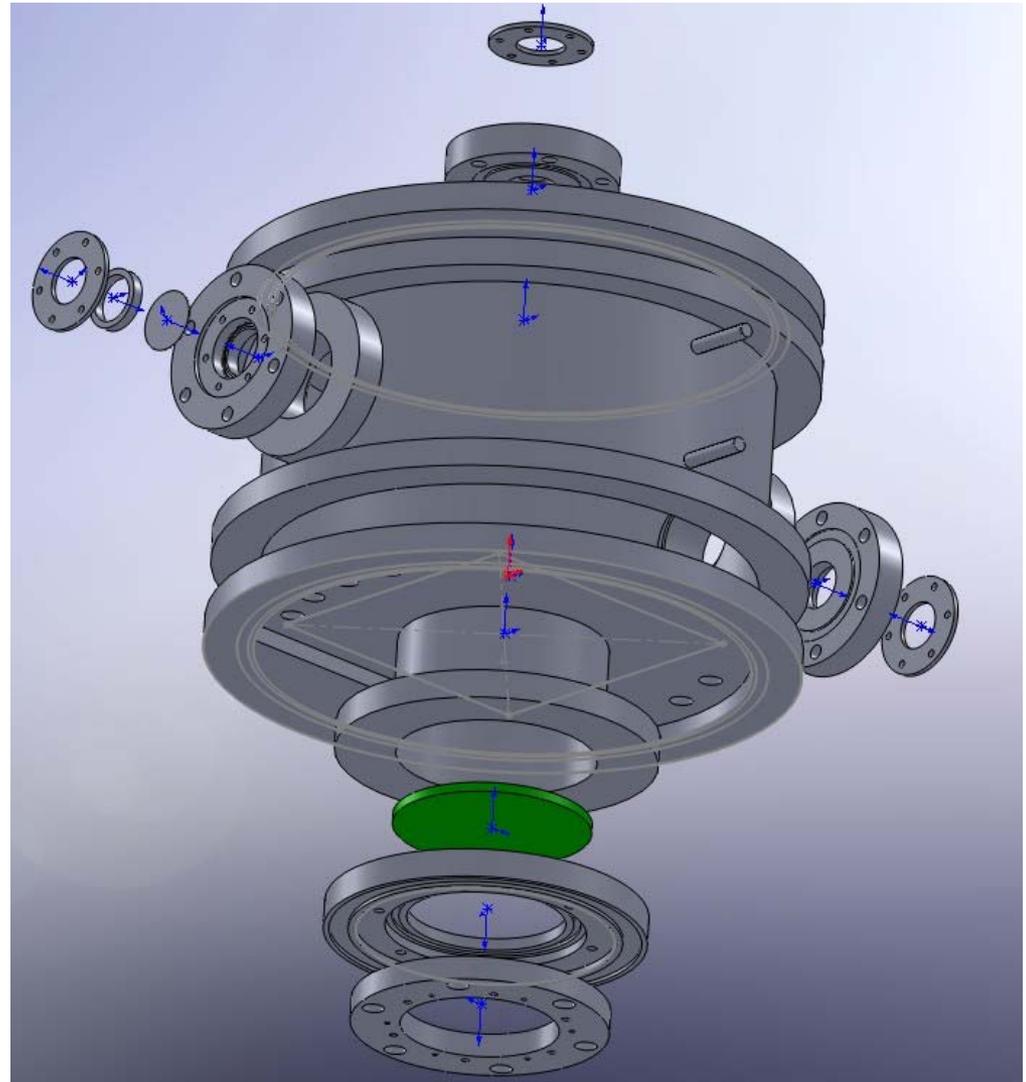
Backup Slides

New "Box"

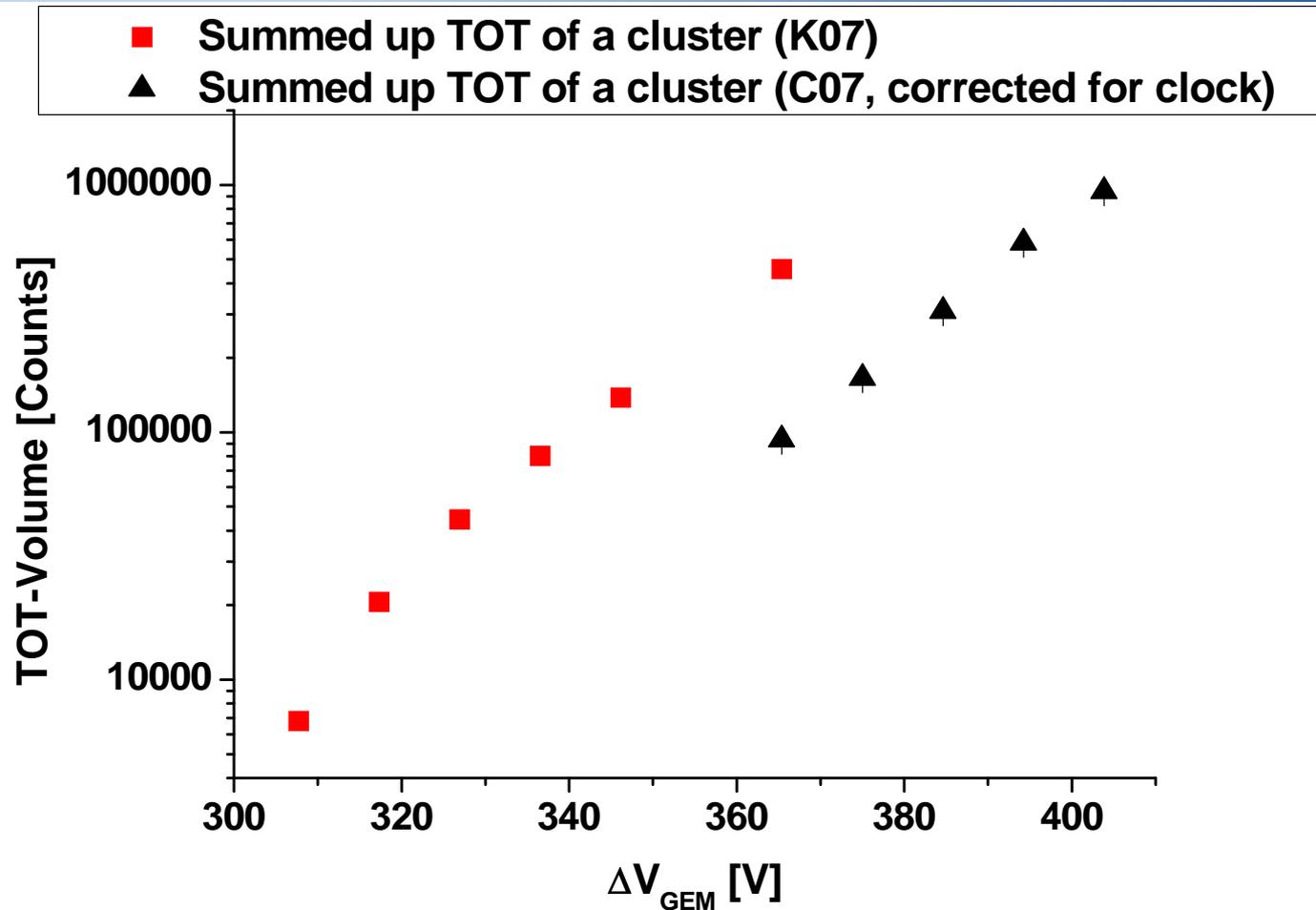


Features

- Modular construction with (adapted) standardized components.
- Avoiding of outgassing components or glue-
- 1" windows for tests with laser, beam or radioactive sources.
- Gas in- & outlets
- 9 SHV channel-feedthroughs
- Electronics connected through a customizable board.
- Sensors for pressure, humidity and temperature.

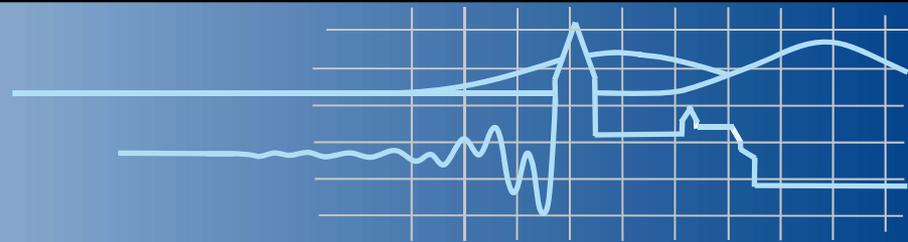


Tot Volumes vs. ΔV_{GEM}



- Values corrected for different clock use with 2x2 (USB/80MHz) and 1x1 (MUROS/37MHz).
- Summed TOT (=TOT Volume) of a cluster proportional to total charge in clusters.
- For comparison different cluster sizes and thresholds must be taken into account.

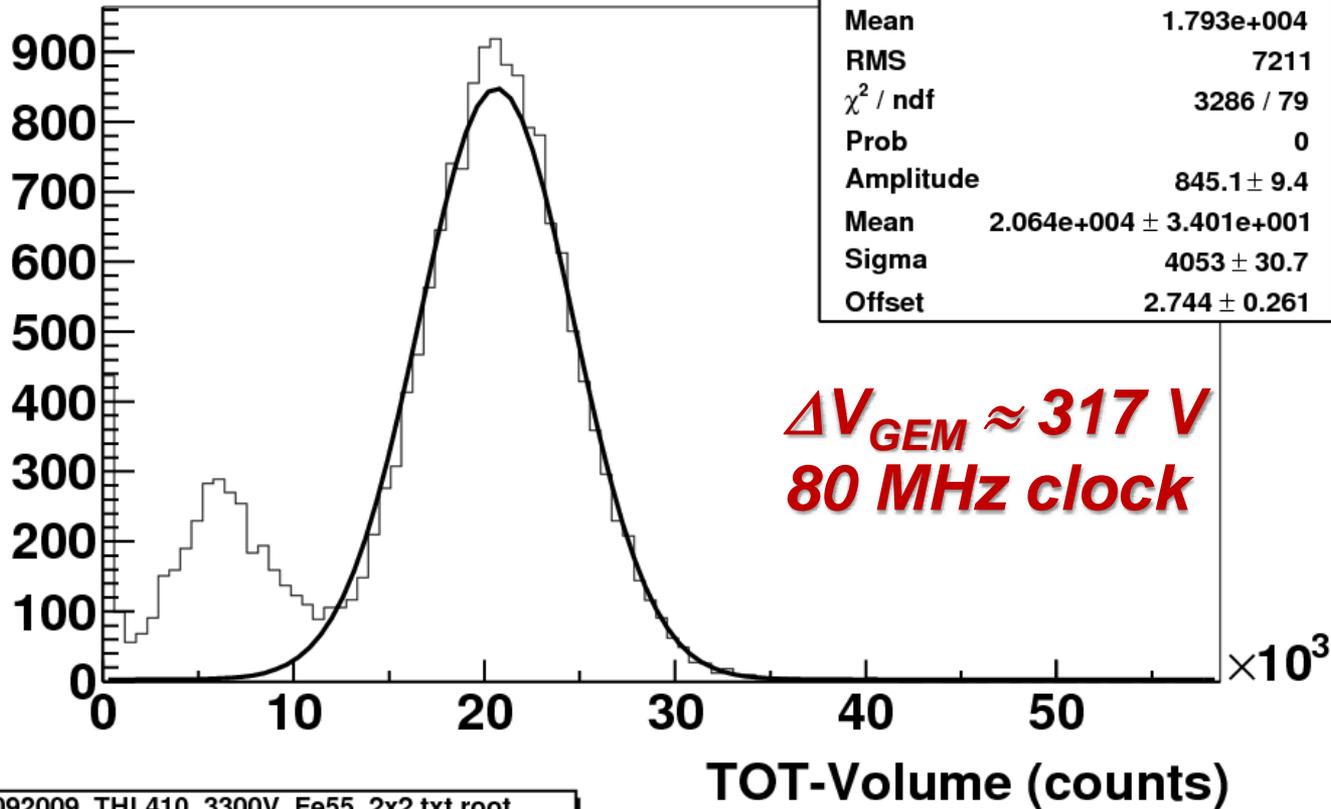
TOT-Volume 2x2



totVolume {eccentr>0.1 && eccentr<0.7}

histTotVolume

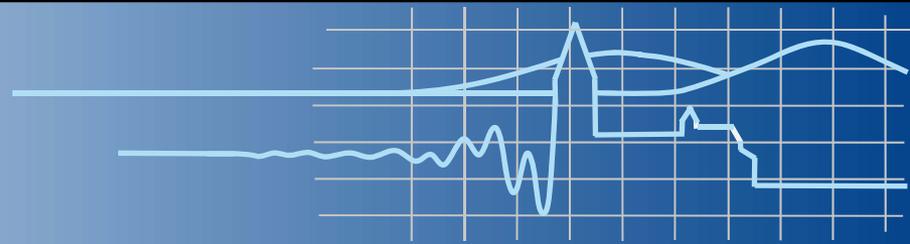
Entries	18317
Mean	1.793e+004
RMS	7211
χ^2 / ndf	3286 / 79
Prob	0
Amplitude	845.1 \pm 9.4
Mean	2.064e+004 \pm 3.401e+001
Sigma	4053 \pm 30.7
Offset	2.744 \pm 0.261



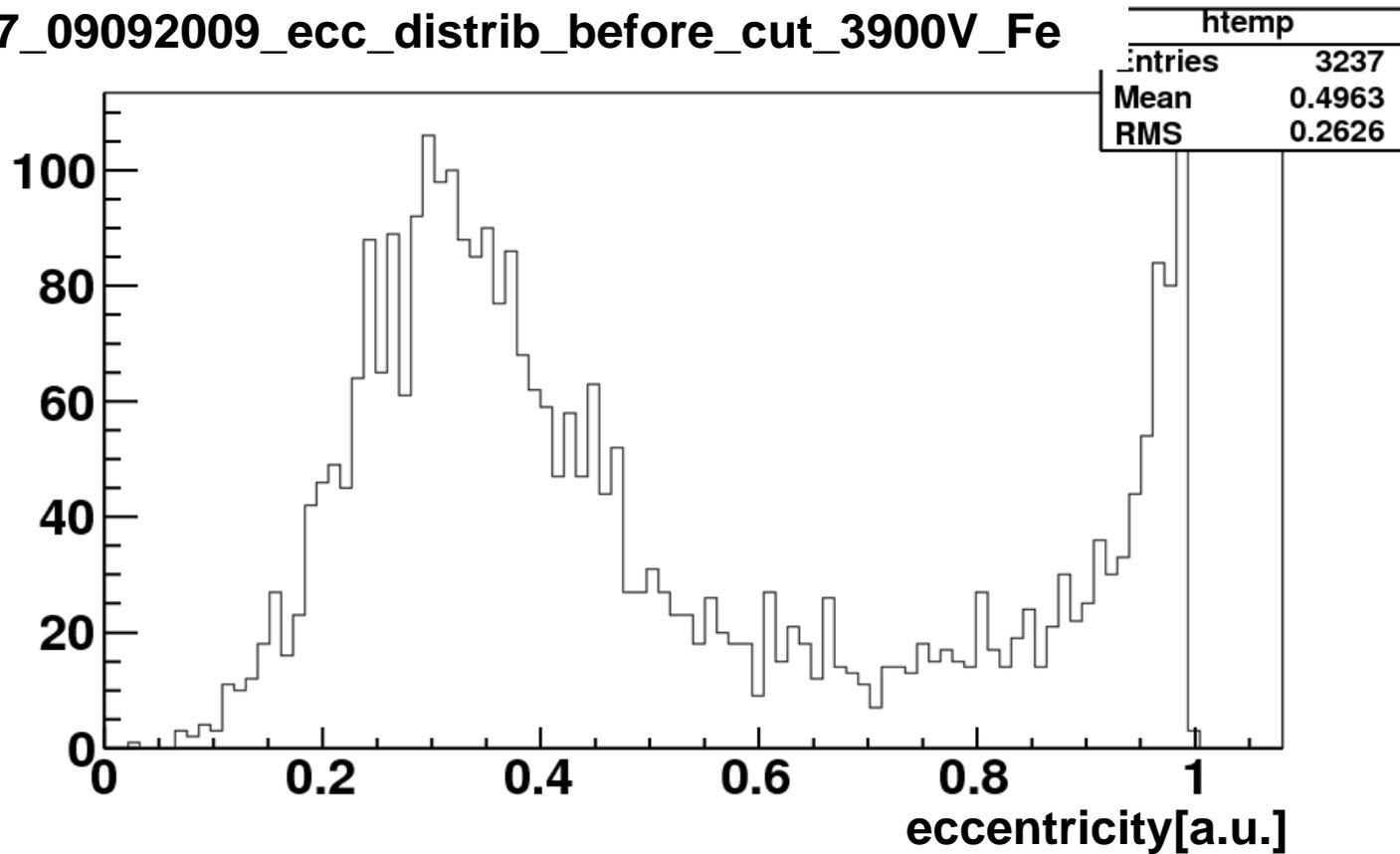
29092009_THL410_3300V_Fe55_2x2.txt.root

**K07 "2x2" TimePix: 16 384 pixels of 110x110 μm^2
 \Rightarrow average cluster size \approx 33 pixels**

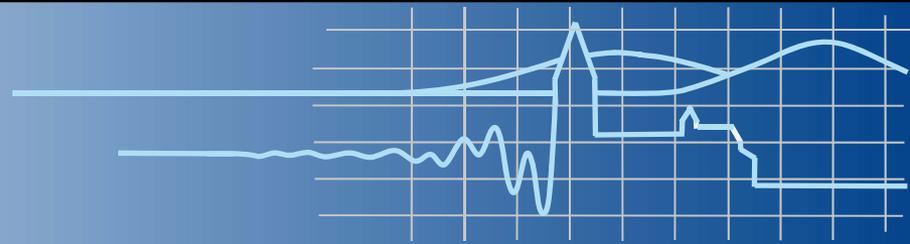
Eccentricity for 1x1



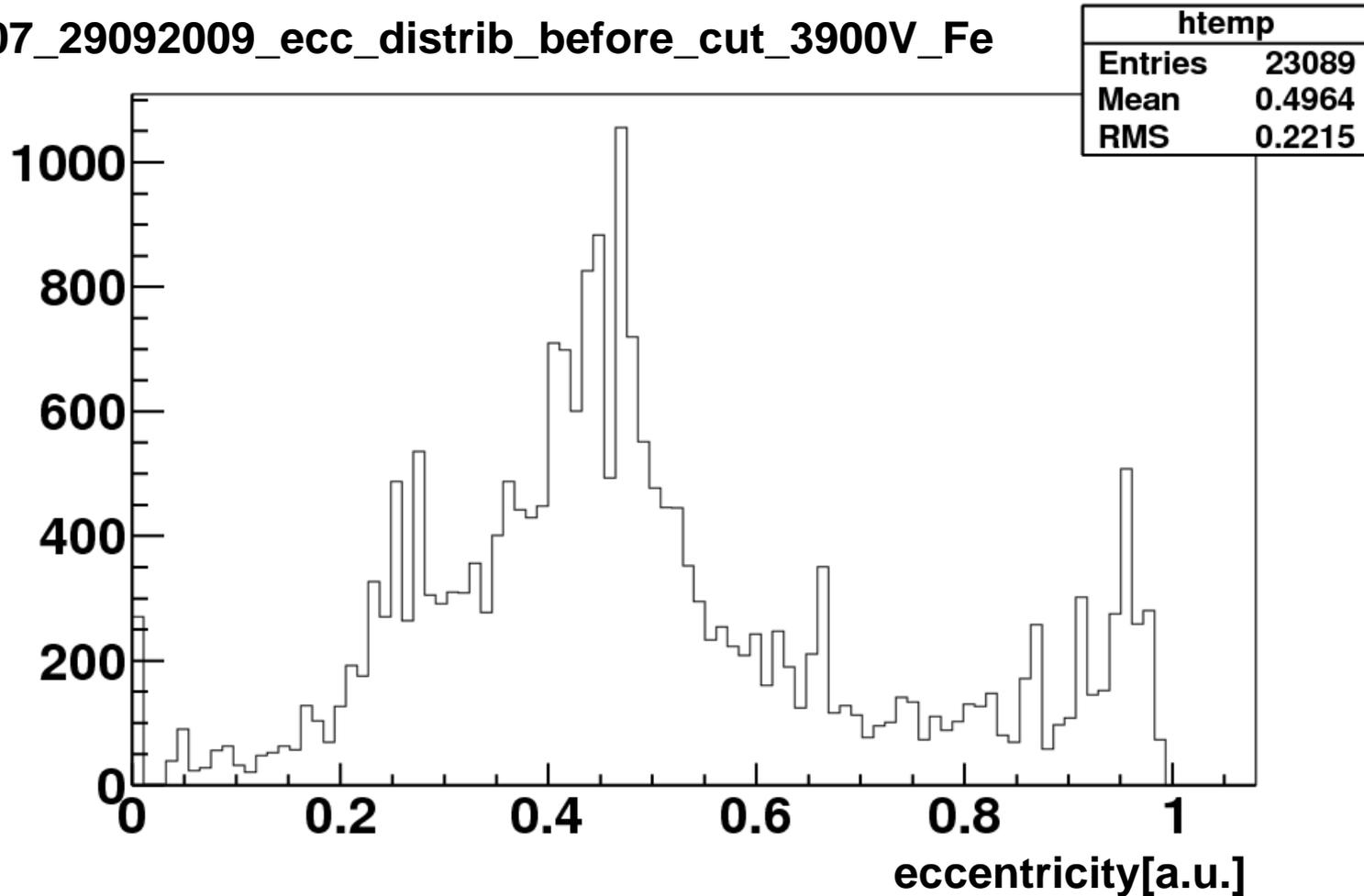
C07_09092009_ecc_distrib_before_cut_3900V_Fe



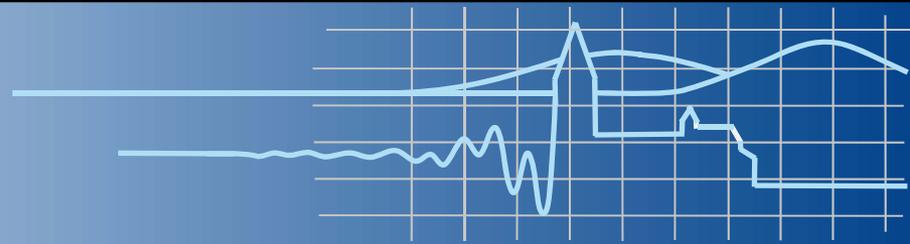
Eccentricity for 2x2



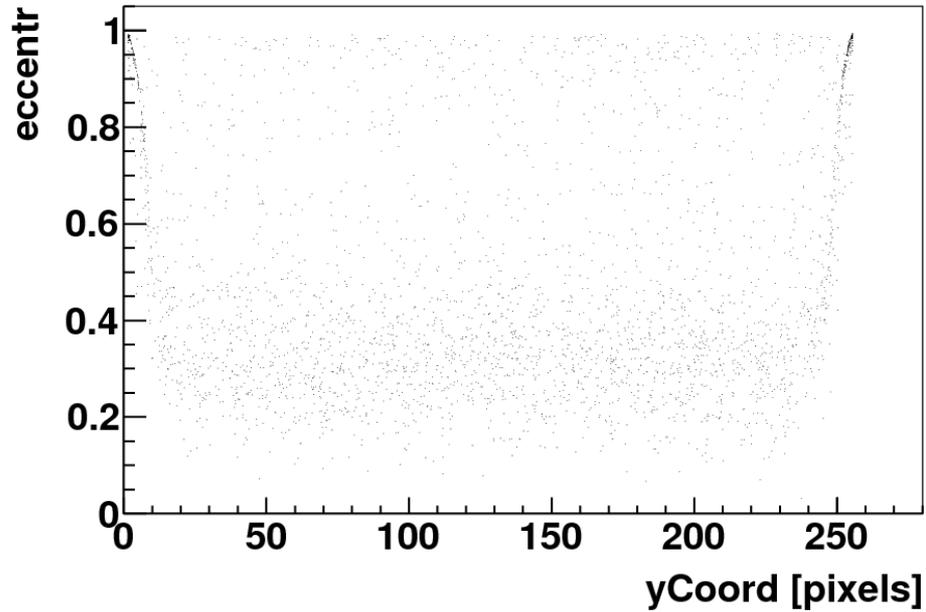
K07_29092009_ecc_distrib_before_cut_3900V_Fe



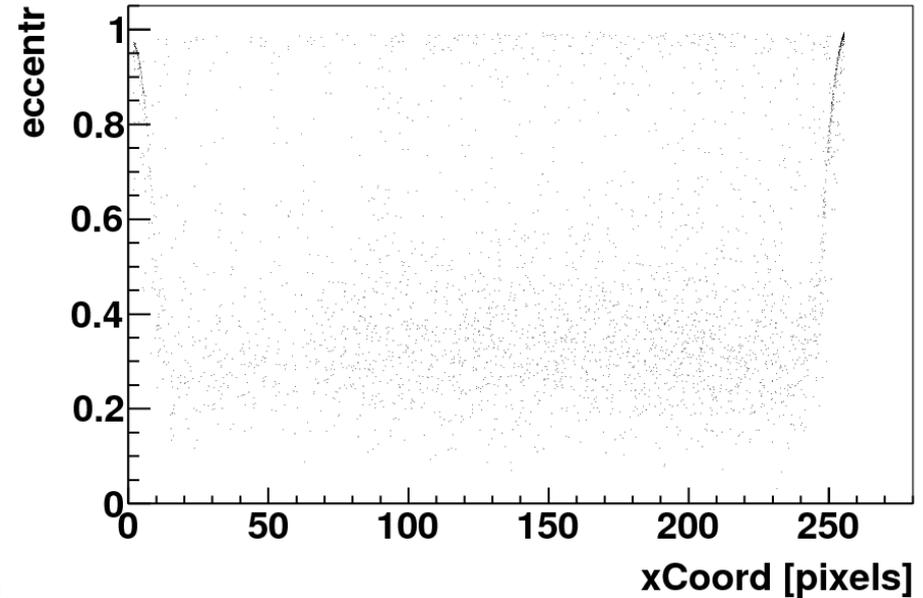
Eccentricity-Position Correlation: C07 3900V



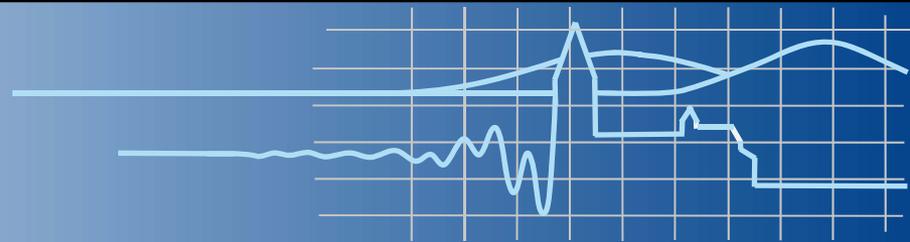
eccentr:yCoord



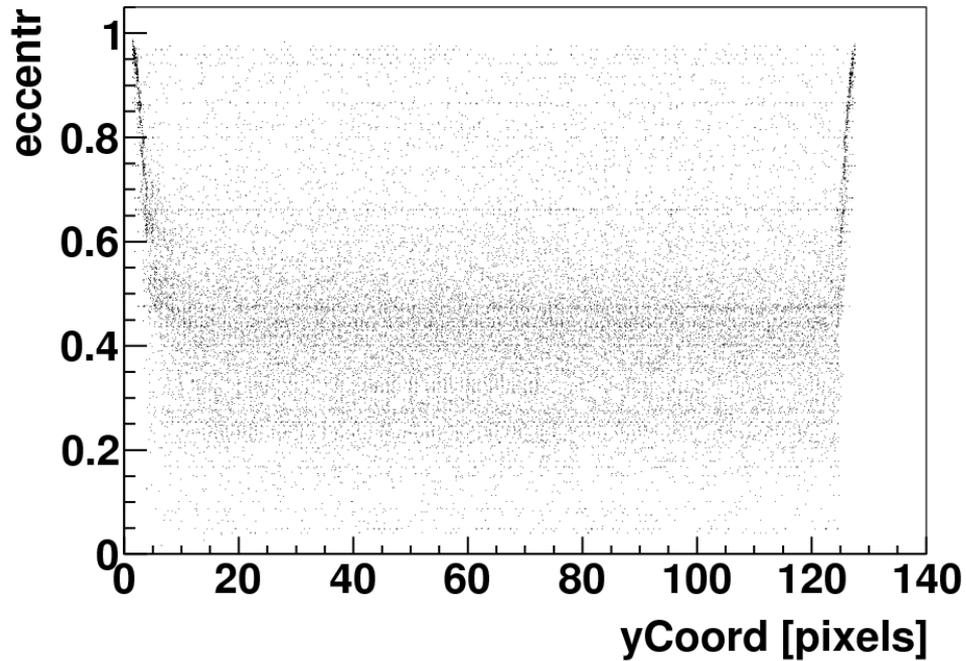
eccentr:xCoord



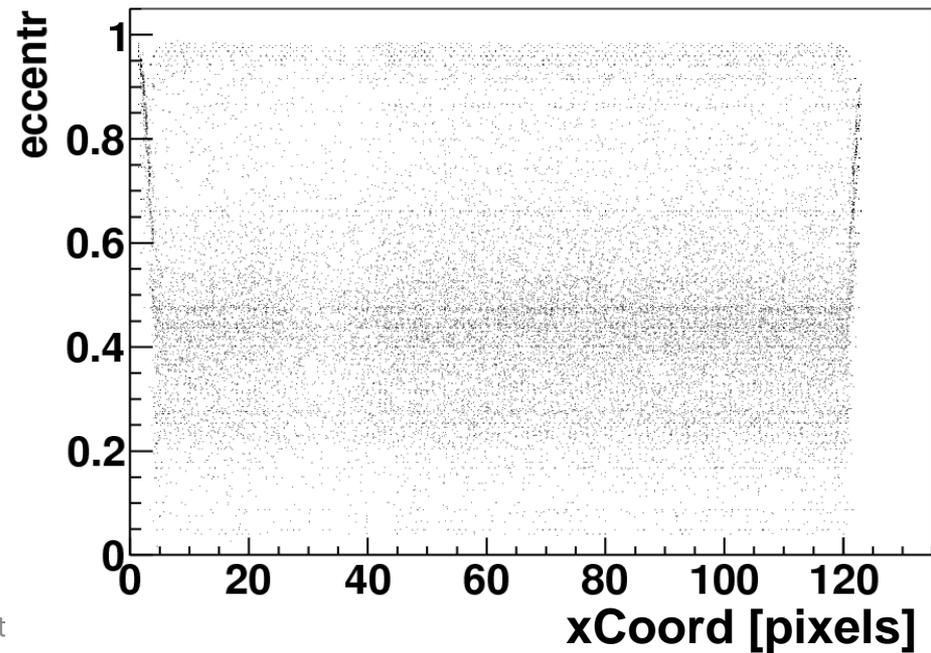
Eccentricity-Position Correlation: K07 3300V



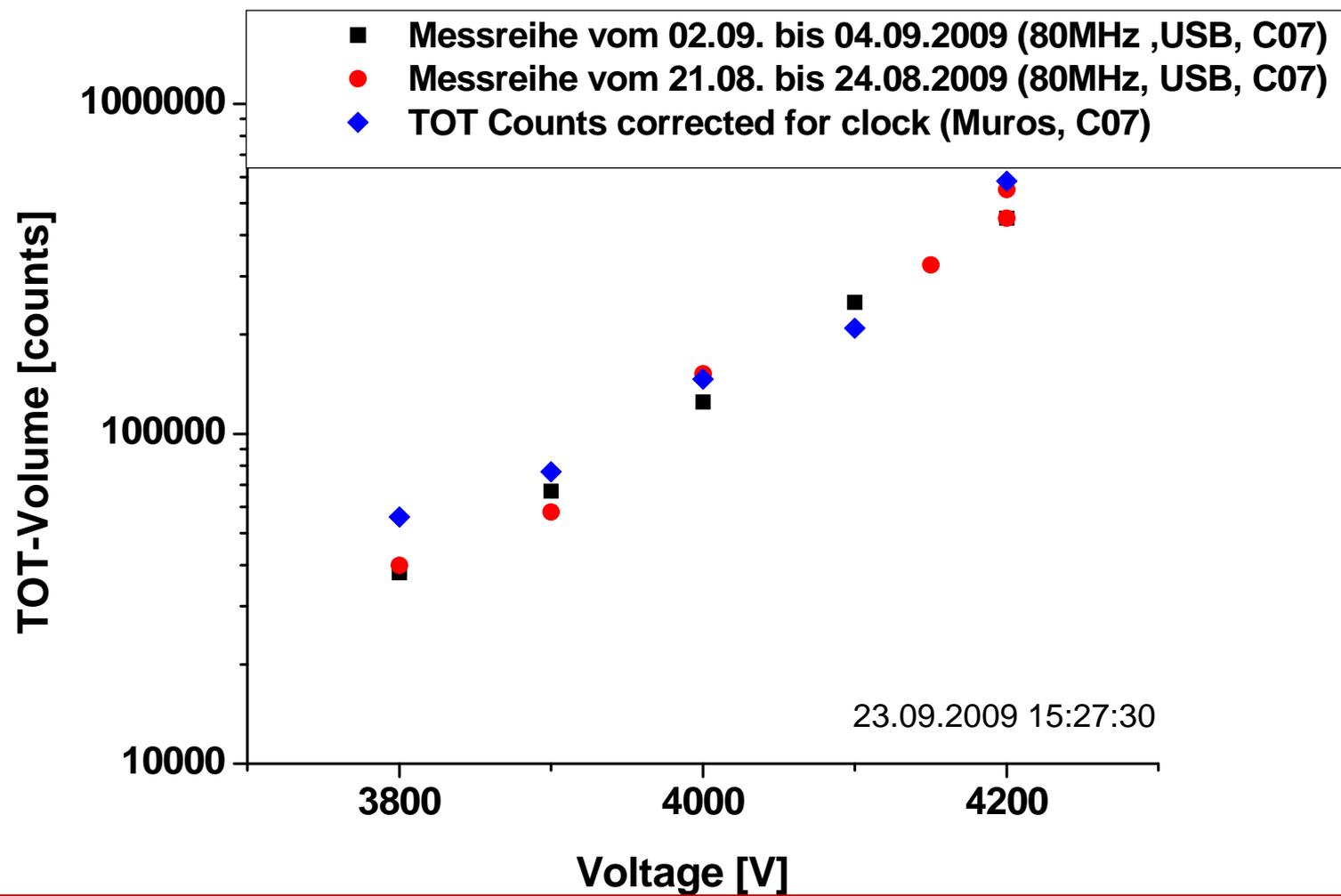
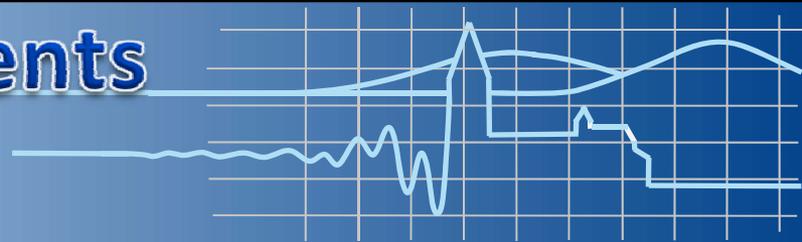
eccentr:yCoord



eccentr:xCoord

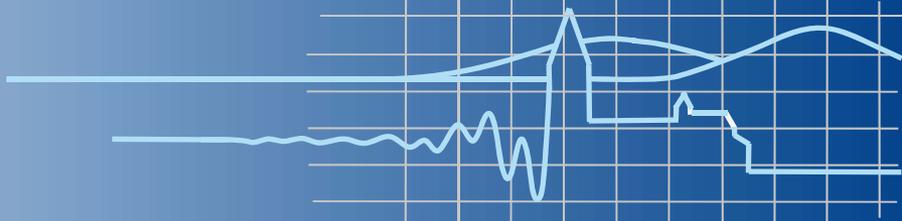


Comparison of Measurements between Muros and USB



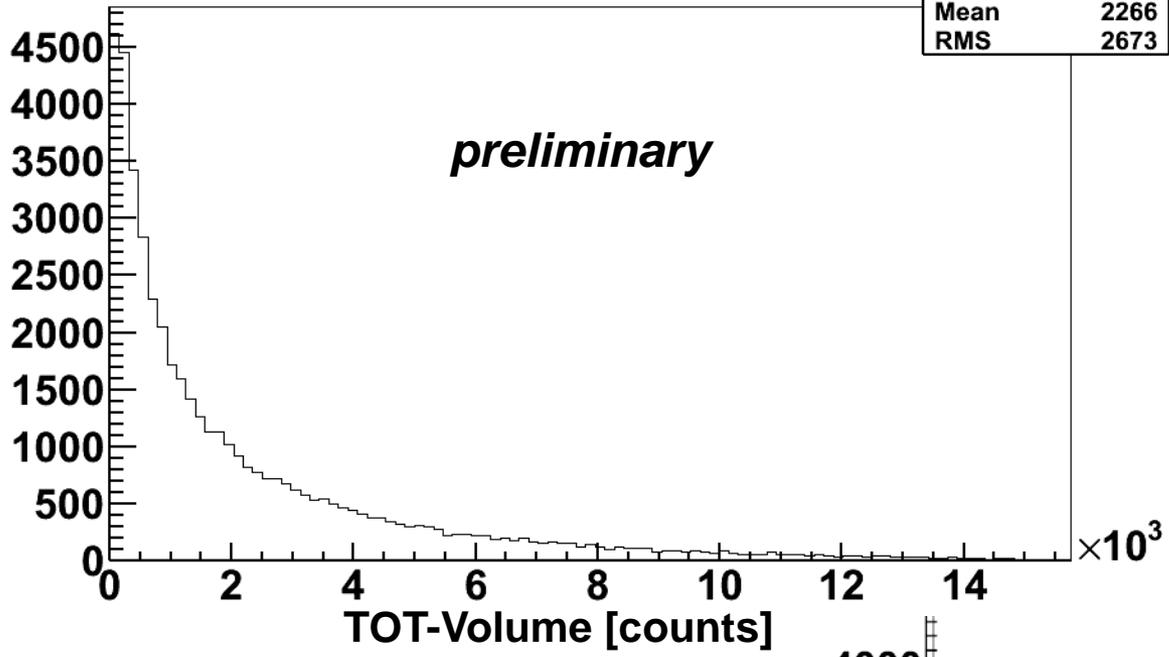
No significant difference between USB and Muros in measurements without test pulse

Laser-Spectra 2x2



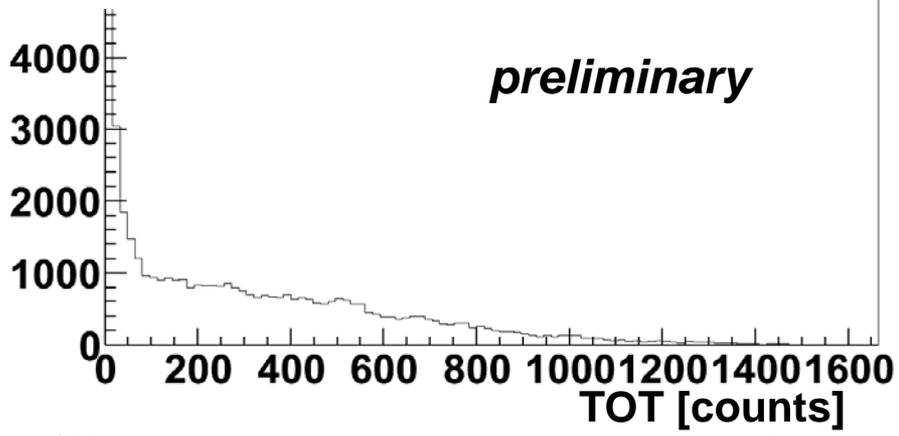
totVolume {eccentr>0.1 && eccentr<0.7 && totVolume <15000}

htemp	
Entries	45556
Mean	2266
RMS	2673

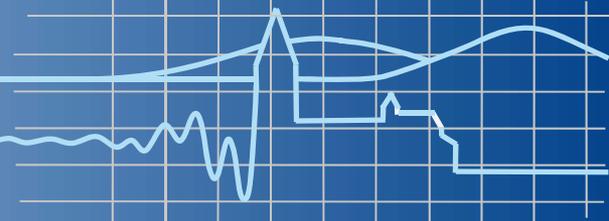


$\Delta V_{\text{GEM}} \approx 317 \text{ V}$
80 MHz clock

htemp	
Entries	45901
Mean	308.6
RMS	303.2

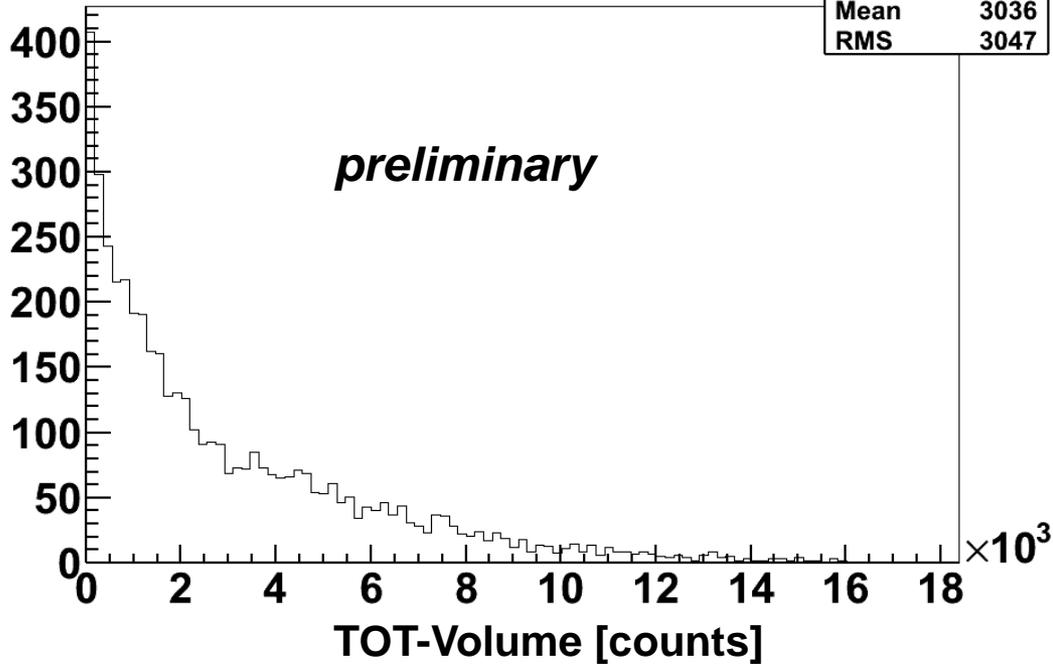


Laser-Spectra-C07 2x2



totVolume {eccentr>0.1 && eccentr<0.7 && totVolume <18000}

htemp	
Entries	4640
Mean	3036
RMS	3047



$\Delta V_{GEM} \approx 375 \text{ V}$
37 MHz clock

sid {eccentr>0.1 && eccentr<0.7 && totVolume <18000}

htemp	
Entries	4640
Mean	80.54
RMS	51.08

